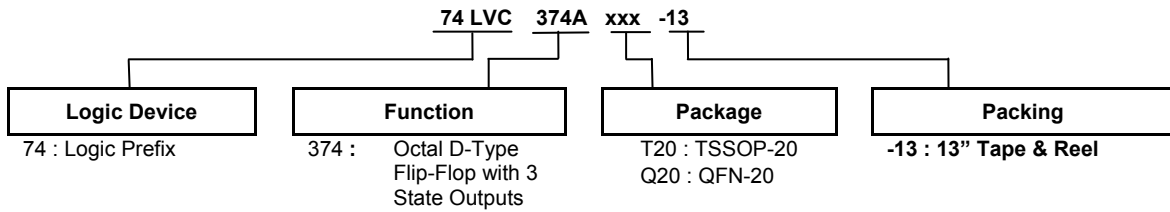


## Ordering Information



Part Number	Package Code	Package (Note 4 & 5)	Package Size	13" Tape and Reel	
				Quantity	Part Number Suffix
74LVC374AT20-13	T20	TSSOP-20	6.4mm X 6.5mm X 1.2mm 0.65 mm lead pitch	2500/Tape & Reel	-13
74LVC374AQ20-13	Q20	V-QFN4525-20	2.5mm X 4.5mm X 0.95mm 0.50 mm lead pitch	2500/Tape & Reel	-13

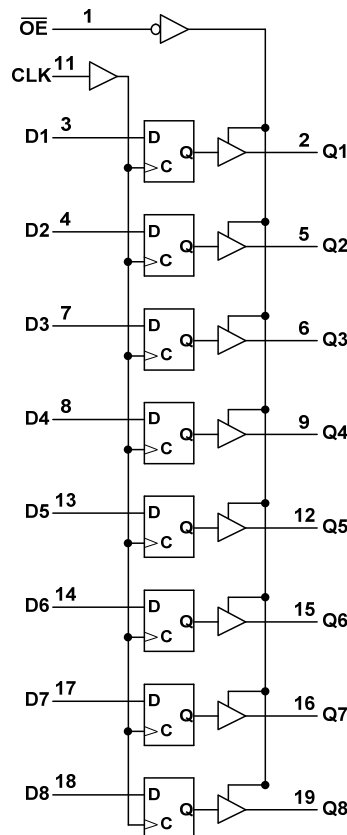
Notes:

4. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
5. V-QFN4525-20 is a JEDEC recognized naming convention that specifies the package thickness category as V and the number 4525 describes the package as 4.5mm X 2.5mm.

## Pin Descriptions

Pin Number	Pin Name	Description
1	OE	Output Enable
2	Q1	Latch Output
3	D1	Data Input
4	D2	Data Input
5	Q2	Latch Output
6	Q3	Latch Output
7	D3	Data Input
8	D4	Data Input
9	Q4	Latch Output
10	GND	Ground
11	CLK	Clock
12	Q5	Latch Output
13	D5	Data Input
14	D6	Data Input
15	Q6	Latch Output
16	Q7	Latch Output
17	D7	Data Input
18	D8	Data Input
19	Q8	Latch Output
20	Vcc	Supply Voltage

## Logic Diagram



## Function Table

(Each Latch)			
INPUTS			OUTPUT
OE	CLK	D	Q
L	↑	H	H
L	↑	L	L
L	H or L	X	Q <sub>0</sub>
H	X	X	Z

**Absolute Maximum Ratings** (Notes 6 & 7)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to +7.0	V
V <sub>I</sub>	Input Voltage Range	-0.5 to +7.0	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> < 0V	-20	mA
I <sub>OK</sub>	Output Clamp Current V <sub>O</sub> < 0V	-50	mA
I <sub>O</sub>	Continuous Output Current -0.5V < V <sub>O</sub> < V <sub>CC</sub> + 0.5V	±50	mA
I <sub>CC</sub>	Continuous Current Through V <sub>CC</sub>	100	mA
I <sub>GND</sub>	Continuous Current Through GND	-100	mA
T <sub>J</sub>	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
P <sub>TOT</sub>	Total Power Dissipation	500	mW

- Notes:
- Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
  - Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.

**Recommended Operating Conditions** (Note 8)

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage	Operating	1.65	3.6	V
		Data Retention Only	1.5	—	V
V <sub>I</sub>	Input Voltage	—	0	5.5	V
V <sub>O</sub>	Output Voltage	—	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-Level Output Current	V <sub>CC</sub> = 1.65V	—	-4	mA
		V <sub>CC</sub> = 2.3V	—	-8	
		V <sub>CC</sub> = 2.7V	—	-12	
		V <sub>CC</sub> = 3.0V	—	-24	
I <sub>OL</sub>	Low-Level Output Current	V <sub>CC</sub> = 1.65V	—	4	mA
		V <sub>CC</sub> = 2.3V	—	8	
		V <sub>CC</sub> = 2.7V	—	12	
		V <sub>CC</sub> = 3.0V	—	24	
Δt/ΔV	Input Transition Rise or Fall Rate	—	—	10	ns/V
T <sub>A</sub>	Operating Free-Air Temperature	—	-40	+125	°C

- Note:
- Unused inputs should be held at V<sub>CC</sub> or ground.

**Electrical Characteristics**

Symbol	Parameter	Test Conditions		V <sub>CC</sub>	T <sub>A</sub> = -40°C to +85°C		T <sub>A</sub> = +85°C to +125°C		Unit
					Min	Max	Min	Max	
V <sub>IH</sub>	High-Level Input Voltage			1.65V to 1.95V	V <sub>CC</sub> X 0.65	—	V <sub>CC</sub> X 0.65	—	V
				2.3V to 2.7V	1.7	—	1.7	—	
				3.0V to 3.6V	2	—	2	—	
V <sub>IL</sub>	Low-Level input voltage			1.65V to 1.95V	—	V <sub>CC</sub> X 0.35	—	V <sub>CC</sub> X 0.35	V
				2.3V to 2.7V	—	0.7	—	0.7	
				3.0V to 3.6V	—	0.8	—	0.8	
V <sub>OH</sub>	High-Level Output Voltage	I <sub>OH</sub> = -50μA		1.65V to 3.6V	V <sub>CC</sub> -0.2	—	V <sub>CC</sub> -0.3	—	
		I <sub>OH</sub> = -4mA		1.65V	1.2	—	1.05	—	
		I <sub>OH</sub> = -8mA		2.3V	1.7	—	1.65	—	V
		I <sub>OH</sub> = -12mA		2.7V	2.2	—	2.05	—	
				3.0V	2.4	—	2.48	—	
		I <sub>OH</sub> = -24mA		3.0V	2.3	—	2.0	—	
V <sub>OL</sub>	Low-Level Output Voltage	I <sub>OL</sub> = 100μA		1.65V to 3.6V	—	0.2	—	0.3	V
		I <sub>OL</sub> = 4mA		1.65V	—	0.45	—	0.65	
		I <sub>OL</sub> = 8mA		2.3V	—	0.60	—	0.80	
		I <sub>OL</sub> = 12mA		2.7V	—	0.40	—	0.60	
		I <sub>OL</sub> = 24mA		3.0V	—	0.55	—	0.80	
I <sub>OFF</sub>	Power Down Leakage Current	V <sub>I</sub> or V <sub>O</sub> = 0 or 5.5V		0V	—	±10	—	20	μA
I <sub>I</sub>	Input Current Control Pins	V <sub>I</sub> =GND or 5.5V		0 to 3.6V	—	±5	—	± 20	μA
I <sub>OZ</sub>	Z-State Current Including Input Current I/O Pins	V <sub>I</sub> = GND or 5.5V V <sub>O</sub> = 0 to 5.5V		3.6V	—	±5	—	± 20	uA
I <sub>CC</sub>	Supply Current	V <sub>I</sub> = GND or V <sub>CC</sub> I <sub>O</sub> = 0		3.6V	—	10	—	40	μA
ΔI <sub>CC</sub>	Additional Supply Current	One input at V <sub>CC</sub> -0.6V I <sub>O</sub> = 0A		2.7V to 3.6V	—	500	—	5000	μA
C <sub>i</sub>	Input Capacitance	Control Pins	V <sub>I</sub> = GND or V <sub>CC</sub>	0V to 3.6V	4.0 typical		4.0 typical		pF
		I/O Pins			5.5 typical		5.5 typical		

## Switching Characteristics

Symbol	Parameter	Test Conditions	V <sub>CC</sub>	T <sub>A</sub> = +25°C			-40°C to +85°C		+85°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
f <sub>MAX</sub>	Maximum Frequency	Figure 1	1.8V ± 0.15V	35	40		35		30		Mhz
			2.5V ± 0.3V	50	60		50		45		
			2.7V	80	100		80		64		
			3.3V ± 0.3V	100	125		100		80		
t <sub>w</sub>	Pulse Width CLK	Figure 1	1.8V ± 0.15V	5.0	2.5		5.0		5.5		ns
			2.5V ± 0.3V	4.0	2.0		4.0		4.5		
			2.7V	3.3	1.7		3.3		3.5		
			3.3V ± 0.3V	3.0	1.5		3.0		3.5		
t <sub>su</sub>	Set-up Time D <sub>N</sub> to CLK	Figure 1	1.8V ± 0.15V	4.0	2.0		4.0		4.5		ns
			2.5V ± 0.3V	3.0	1.5		3.0		3.5		
			2.7V	2.0	1.0		2.0		2.5		
			3.3V ± 0.3V	2.0	1.0		2.0		2.5		
t <sub>h</sub>	Hold Time D <sub>N</sub> to CLK	Figure 1	1.8V ± 0.15V	3.0	1.5		3.0		3.5		ns
			2.5V ± 0.3V	2.0	1.0		2.0		2.5		
			2.7V	1.5	1.0		1.5		2.0		
			3.3V ± 0.3V	1.5	1.0		1.5		2.0		
t <sub>PD</sub>	Propagation Delay CLK to Q <sub>N</sub>	Figure 1	1.8V ± 0.15V	1	6	12.2	1	13.5	1	16.9	ns
			2.5V ± 0.3V	1	3.9	8.5	1	9.0	1	8.7	
			2.7V	1	4.2	7.8	1	8.1	1	9.5	
			3.3V ± 0.3V	1.5	3.8	6.8	1.5	7.0	1.5	8.0	
t <sub>EN</sub>	Enable Time $\overline{OE}$ to Q <sub>N</sub>	Figure 1	1.8V ± 0.15V	1	7.8	16.5	1	17	1	14.2	ns
			2.5V ± 0.3V	1	4	9	1	9.5	1	8.2	
			2.7V	1	4.4	8.3	1	8.5	1	10.0	
			3.3V ± 0.3V	1.7	4.1	7.3	1.7	7.5	1.7	9.0	
t <sub>DIS</sub>	Disable Time $\overline{OE}$ to Q <sub>N</sub>	Figure 1	1.8V ± 0.15V	1	7.8	16.5	1	17	1	14.2	ns
			2.5V ± 0.3V	1	4	9	1	9.5	1	8.2	
			2.7V	1	4.4	8.3	1	8.5	1	10.0	
			3.3V ± 0.3V	1.7	4.1	7.3	1.7	7.5	1.7	9.0	
t <sub>DIS</sub>	Disable Time $\overline{OE}$ to Q <sub>N</sub>	Figure 1	1.8V ± 0.15V	1	7.8	16.5	1	17	1	14.2	ns
			2.5V ± 0.3V	1	4	9	1	9.5	1	8.2	
			2.7V	1	4.4	8.3	1	8.5	1	10.0	
			3.3V ± 0.3V	1.7	4.1	7.3	1.7	7.5	1.7	9.0	
tsk(0)	Output Skew Time		3.3V ± 0.3V			1.0				1.5	ns

## Operating Characteristics

 T<sub>A</sub> = +25°C

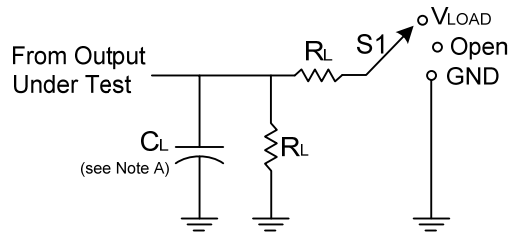
Symbol	Parameter	Test Conditions	V <sub>CC</sub>	Typ	Unit
C <sub>pd</sub>	Power dissipation capacitance per gate	F = 10 MHz Outputs Enabled	1.8V ± 0.15V	9.9	pF
			2.5V ± 0.3V	10.2	
			3.3V ± 0.3V	10.6	

## Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Typ	Max	Unit
θ <sub>JA</sub>	Thermal Resistance Junction-to-Ambient	TSSOP-20	(Note 9)	—	74	—	°C/W
θ <sub>JC</sub>	Thermal Resistance Junction-to-Case	TSSOP-20	(Note 9)	—	15	—	°C/W
θ <sub>JA</sub>	Thermal Resistance Junction-to-Ambient	V-QFN4525-20	(Note 9)	—	67	—	°C/W
θ <sub>JC</sub>	Thermal Resistance Junction-to-Case	V-QFN4525-20	(Note 9)	—	20	—	°C/W

Note: 9. Test conditions for TSSOP-20 and V-QFN4525-20: Devices mounted on 4 layer FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout per JESD 51-7.

## Parameter Measurement Information

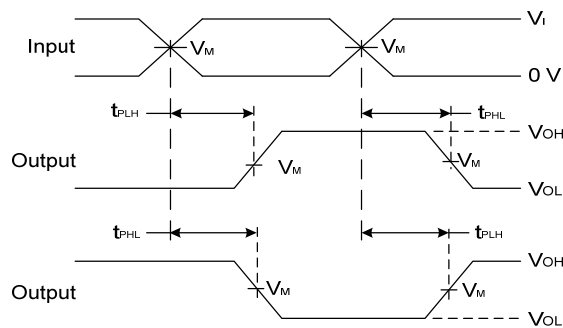


TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	$V_{LOAD}$
$t_{PHZ}/t_{PZH}$	GND

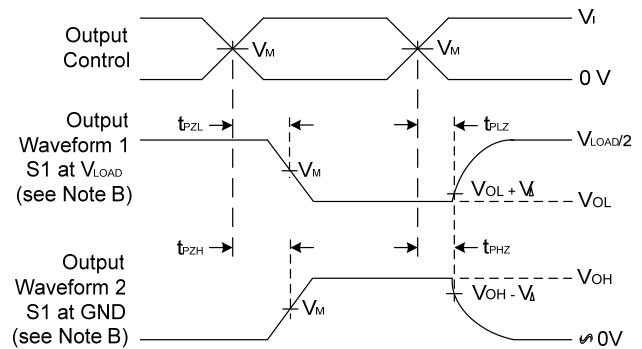
$V_{CC}$	Inputs		$V_M$	$V_{LOAD}$	$C_L$	$R_L$	$V_{\Delta}$
	$V_I$	$t_r/t_f$					
$1.8V \pm 0.15V$	$V_{CC}$	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	30pF	1K $\Omega$	0.15V
$2.5V \pm 0.2V$	$V_{CC}$	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	30pF	500 $\Omega$	0.15V
2.7V	2.7V	$\leq 2.5ns$	1.5V	6V	50pF	500 $\Omega$	0.3V
$3.3V \pm 0.3V$	2.7V	$\leq 2.5ns$	1.5V	6V	50pF	500 $\Omega$	0.3V



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times  
Inverting and Non Inverting Outputs



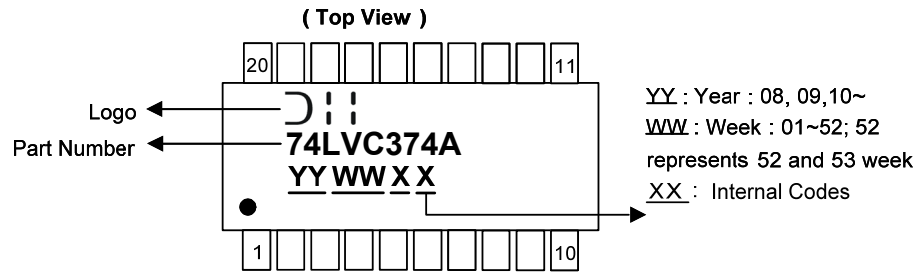
Voltage Waveform Enable and Disable Times  
Low and High Level Enabling

- Notes:
- A. Includes test lead and test apparatus capacitance.
  - B. All pulses are supplied at pulse repetition rate  $\leq 10$  MHz.
  - C. Inputs are measured separately one transition per measurement.
  - D.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - E.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{ENO}$ .
  - F.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD}$ .

Figure 1 Load Circuit and Voltage Waveforms

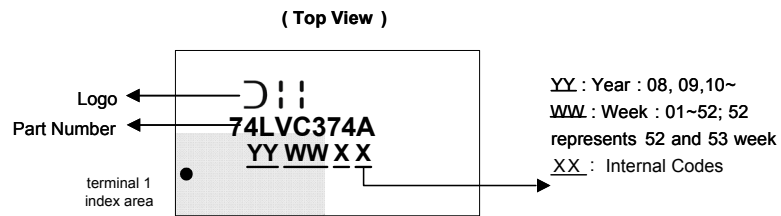
## Marking Information

### (1) TSSOP20



Part Number	Package
74LVC374AT20	TSSOP-20

### (2) QFN-20 (V-QFN4525-20)

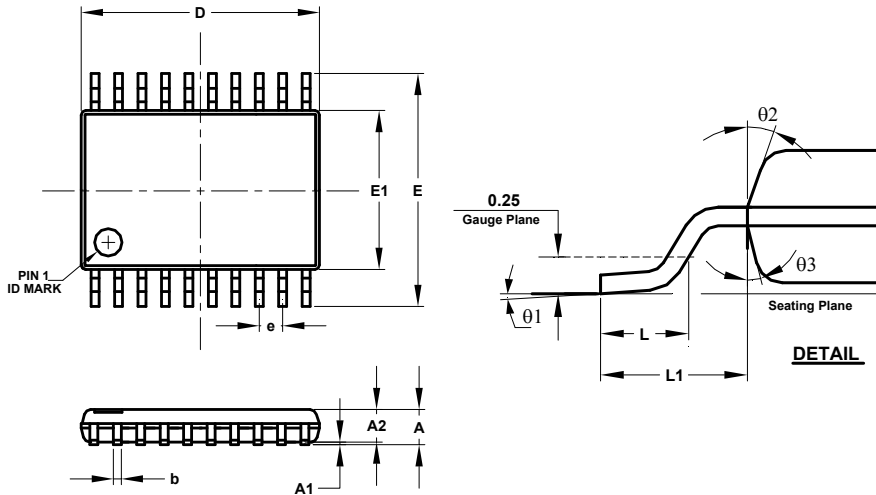


Part Number	Package
74LVC374AQ20	V-QFN4525-20

# Package Outline Dimensions (All Dimensions in mm)

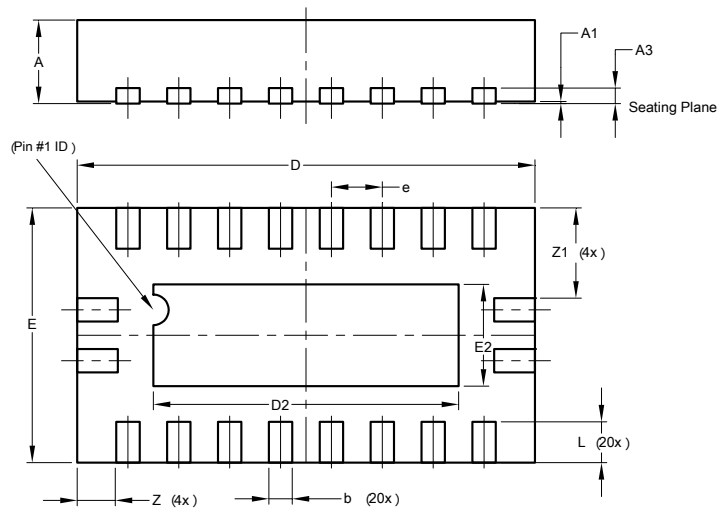
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.

## (1) TSSOP-20



TSSOP-20			
Dim	Min	Max	Typ
A	-	1.20	-
A1	0.05	0.15	-
A2	0.80	1.05	-
b	0.19	0.30	-
c	0.09	0.20	-
D	6.40	6.60	6.50
E	6.20	6.60	6.40
E1	4.30	4.50	4.40
e	0.65 BSC		
L	0.45	0.75	0.60
L1	1.0 REF		
θ1	0°	8°	-
θ2	10°	14°	12°
θ3	10°	14°	12°
All Dimensions in mm			

## (2) QFN-20 (V-QFN4525-20)

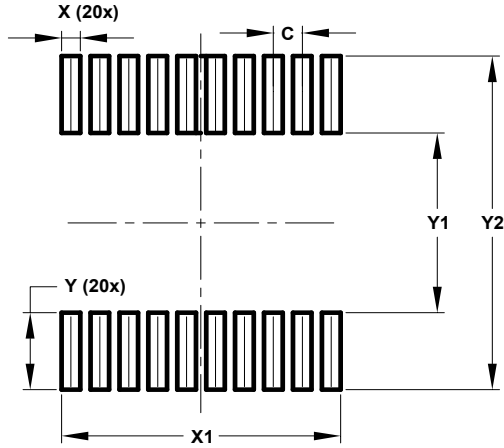


V-QFN4525-20			
Dim	Min	Max	Typ
A	0.75	0.85	0.80
A1	0.00	0.05	0.02
A3	-	-	0.15
b	0.18	0.30	0.23
D	4.45	4.55	4.50
D2	2.85	3.15	3.00
E	2.45	2.55	2.50
E2	0.85	1.15	1.00
e	0.50BSC		
L	0.30	0.50	0.40
Z	-	-	0.385
Z1	-	-	0.885
All Dimensions in mm			

## Suggested Pad Layout

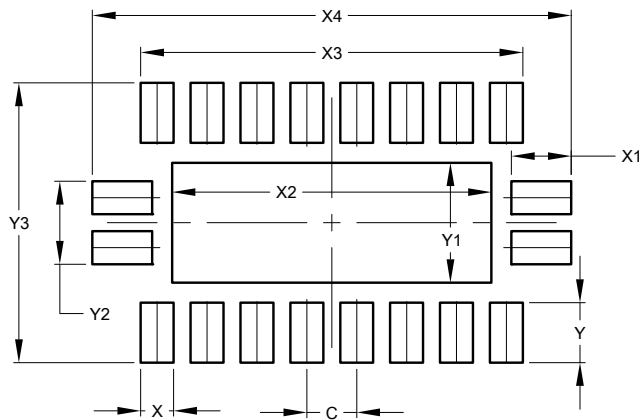
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

### (1) TSSOP-20



Dimensions	Value (in mm)
C	0.650
X	0.420
X1	6.270
Y	1.789
Y1	4.160
Y2	7.720

### (2) QFN-20 (V-QFN4525-20)



Dimensions	Value (in mm)
C	0.500
X	0.330
X1	0.600
X2	3.200
X3	3.830
X4	4.800
Y	0.600
Y1	1.200
Y2	0.830
Y3	2.800



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